



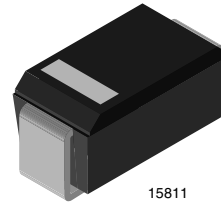
## Surface Mount Zener Diodes

### FEATURES

- Plastic package has underwriters laboratory flammability classification 94 V-0
- For surface mounted applications
- Low Zener impedance
- Low regulation factor
- High temperature soldering guaranteed: 260 °C/10 s at terminals
- Standard voltage tolerance is 10 %, suffix A  $\pm$  5 %
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



**RoHS**  
COMPLIANT



15811

### MECHANICAL DATA

**Case:** JEDEC DO-214AC molded plastic over passivated junction

**Terminals:** solder plated, solderable per MIL-STD- 750, method 2026

**Polarity:** color band denotes positive end (cathode)

**Mounting Position:** any

**Weight:** 0.002 ounce, 64 mg

### Packaging Codes/Options (antistatic):

SML4728 - SML4764A:

61 to 1.8K per 7" plastic reel (12 mm tape)

5A to 7.5K per 13" plastic reel (12 mm tape)

### Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Power dissipation	$T_L = 75\text{ }^{\circ}\text{C}$	$P_{tot}$	1.0	W

### Thermal Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Maximum junction temperature		$T_j$	150	$^{\circ}\text{C}$
Storage temperature range		$T_s$	- 65 to + 150	$^{\circ}\text{C}$

# SML4728 to SML4764A



Vishay Semiconductors

## Electrical Characteristics

Partnumber	Device Marking Code	Nominal Zener Voltage	Test Current	Maximum Dynamic ImpedanceResistance			Maximum DC Reverse Leakage Current		Maximum Surge Current
				$V_Z^{(1)}$ at $I_{ZT}$	$I_{ZT}$	$Z_{ZT}$ at $I_{ZT}$	$Z_{ZK}$ at $I_{ZK}$	$I_{ZK}$	
		V	mA	$\Omega$	$\Omega$	mA	$\mu A$	V	mApk
SML4728	3P3	3.3	76	10	400	1	100	1	1380
SML4729	3P6	3.6	69	10	400	1	100	1	1260
SML4730	3P9	3.9	64	9	400	1	50	1	1190
SML4731	4P3	4.3	58	9	400	1	10	1	1070
SML4732	4P7	4.7	53	8	500	1	10	1	970
SML4733	5P1	5.1	49	7	550	1	10	1	890
SML4734	5P6	5.6	45	5	600	1	10	2	810
SML4735	6P2	6.2	41	2	700	1	10	3	730
SML4736	6P8	6.8	37	3.5	700	1	10	4	660
SML4737	7P5	7.5	34	4	700	0.5	10	5	605
SML4738	8P2	8.2	31	4.5	700	0.5	10	6	550
SML4739	9P1	9.1	28	5	700	0.5	10	7	500
SML4740	10	10	25	7	700	0.25	10	7.6	454
SML4741	11	11	23	8	700	0.25	5	8.4	414
SML4742	12	12	21	9	700	0.25	5	9.1	380
SML4743	13	13	19	10	700	0.25	5	9.9	344
SML4744	15	15	17	14	700	0.25	5	11.4	305
SML4745	16	16	15.5	16	700	0.25	5	12.2	285
SML4746	18	18	14	20	750	0.25	5	13.7	250
SML4747	20	20	12.5	22	750	0.25	5	15.2	225
SML4748	22	22	11.5	23	750	0.25	5	16.7	205
SML4749	24	24	10.5	25	750	0.25	5	18.2	190
SML4750	27	27	9.5	35	750	0.25	5	20.6	170
SML4751	30	30	8.5	40	1000	0.25	5	22.8	150
SML4752	33	33	7.5	45	1000	0.25	5	25.1	135
SML4753	36	36	7	50	1000	0.25	5	27.4	125
SML4754	39	39	6.5	60	1000	0.25	5	29.7	115
SML4755	43	43	6	70	1500	0.25	5	32.7	110
SML4756	47	47	5.5	80	1500	0.25	5	35.8	95
SML4757	51	51	5	95	1500	0.25	5	38.8	90
SML4758	56	56	4.5	110	2000	0.25	5	42.6	80
SML4759	62	62	4	125	2000	0.25	5	47.1	70
SML4760	68	68	3.7	150	2000	0.25	5	51.7	65
SML4761	75	75	3.3	175	2000	0.25	5	56	60
SML4762	82	82	3	200	3000	0.25	5	62.2	55
SML4763	91	91	2.8	250	3000	0.25	5	69.2	50
SML4764	100	100	2.5	350	3000	0.25	5	76	45

Notes:

(1) Based on dc- measurement at thermal equilibrium

(2) Surge current is a non-repetitive, 8.3 ms pulse width square wave or equivalent sine-wave superimposed on  $I_{ZT}$  per JEDEC method

## TYPICAL CHARACTERISTICS

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

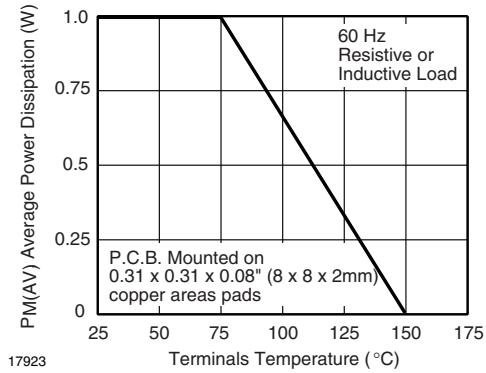


Fig. 1 - Maximum Continuous Power Dissipation

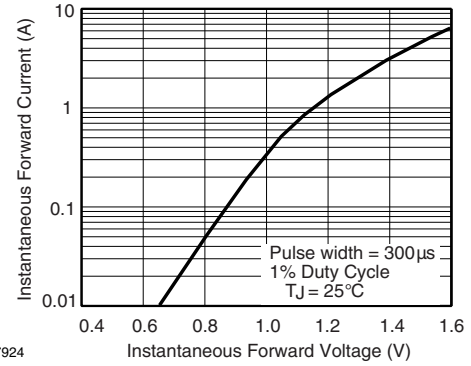


Fig. 4 - Typical Instantaneous Forward Characteristics for SML4763

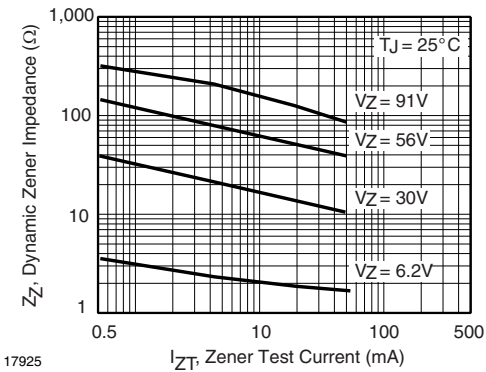


Fig. 2 - Typical Zener Impedance

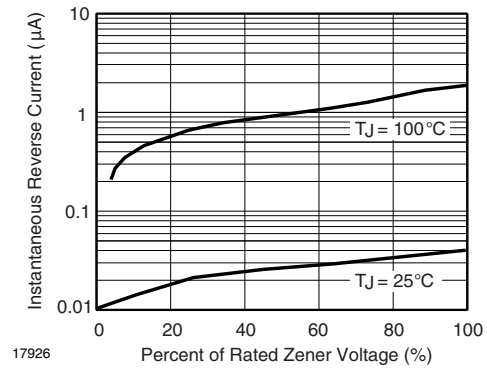


Fig. 5 - Typical Reverse Characteristics

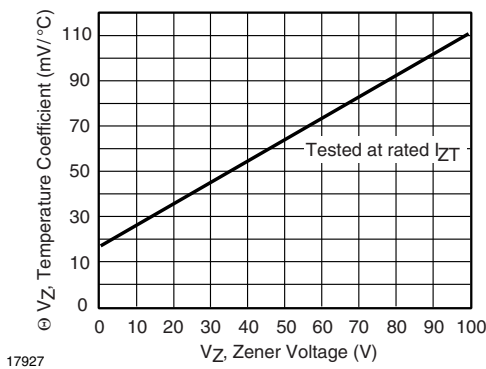


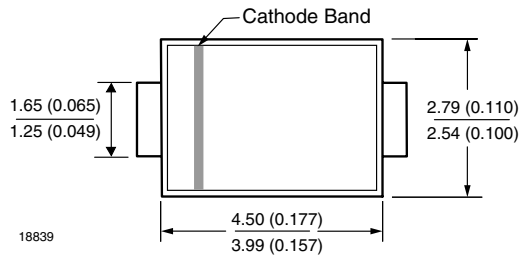
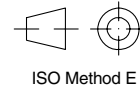
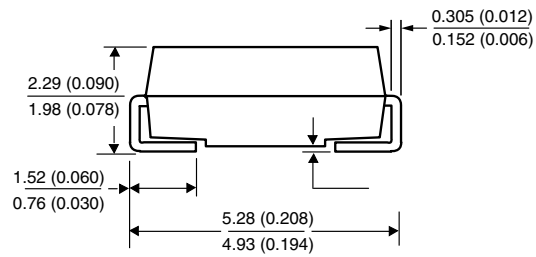
Fig. 3 - Typical Temperature Coefficients

# SML4728 to SML4764A

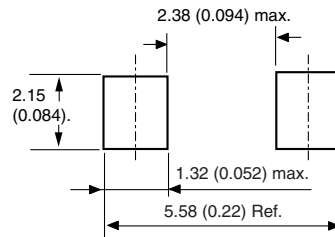


Vishay Semiconductors

## PACKAGE DIMENSIONS in millimeters (Inches)



### Mounting Pad Layout





## Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design  
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



## Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.